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# FDP16AN08A0

## N-Channel PowerTrench® MOSFET

75 V, 58 A, 16 mΩ

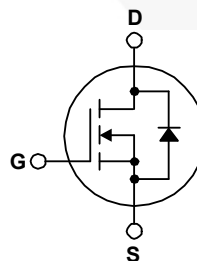
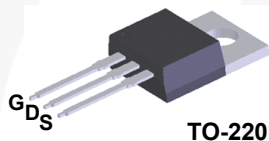
### Features

- $R_{DS(on)} = 13 \text{ m}\Omega$  (Typ.) @  $V_{GS} = 10 \text{ V}$ ,  $I_D = 58 \text{ A}$
- $Q_{G(tot)} = 28 \text{ nC}$  (Typ.) @  $V_{GS} = 10 \text{ V}$
- Low Miller Charge
- Low  $Q_{rr}$  Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)

### Applications

- Synchronous Rectification for ATX / Server / Telecom PSU
- Battery Protection Circuit
- Motor Drives and Uninterruptible Power Supplies

Formerly developmental type 82660



### MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	FDP16AN08A0	Unit
$V_{DSS}$	Drain to Source Voltage	75	V
$V_{GS}$	Gate to Source Voltage	$\pm 20$	V
$I_D$	Drain Current		
	Continuous ( $T_C = 25^\circ\text{C}$ , $V_{GS} = 10\text{V}$ )	58	A
	Continuous ( $T_C = 100^\circ\text{C}$ , $V_{GS} = 10\text{V}$ )	44	
	Continuous ( $T_{amb} = 25^\circ\text{C}$ , $V_{GS} = 10\text{V}$ , with $R_{\theta JA} = 43^\circ\text{C/W}$ )	9	A
	Pulsed	Figure 4	A
$E_{AS}$	Single Pulse Avalanche Energy (Note 1)	117	mJ
$P_D$	Power dissipation	135	W
	Derate above $25^\circ\text{C}$	0.9	W/ $^\circ\text{C}$
$T_J, T_{STG}$	Operating and Storage Temperature	-55 to 175	$^\circ\text{C}$

### Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case, Max.	1.11	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (Note 2), Max.	62	$^\circ\text{C/W}$

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP16AN08A0	FDP16AN08A0	TO-220	Tube	N/A	50 units

## Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
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### Off Characteristics

$B_{VDSS}$	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}, V_{GS} = 0\text{V}$	75	-	-	V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 60\text{V}$ $V_{GS} = 0\text{V}$ $T_C = 150^\circ\text{C}$	-	-	1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 20\text{V}$	-	-	$\pm 100$	nA

### On Characteristics

$V_{GS(TH)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\mu\text{A}$	2	-	4	V
$r_{DS(ON)}$	Drain to Source On Resistance	$I_D = 58\text{A}, V_{GS} = 10\text{V}$	-	0.013	0.016	$\Omega$
		$I_D = 29\text{A}, V_{GS} = 6\text{V}$	-	0.019	0.029	
		$I_D = 58\text{A}, V_{GS} = 10\text{V},$ $T_J = 175^\circ\text{C}$	-	0.032	0.037	

### Dynamic Characteristics

$C_{ISS}$	Input Capacitance	$V_{DS} = 25\text{V}, V_{GS} = 0\text{V},$ $f = 1\text{MHz}$	-	1857	-	pF	
$C_{OSS}$	Output Capacitance		-	288	-	pF	
$C_{RSS}$	Reverse Transfer Capacitance		-	88	-	pF	
$Q_{g(TOT)}$	Total Gate Charge at 10V	$V_{GS} = 0\text{V to } 10\text{V}$	$V_{DD} = 40\text{V}$ $I_D = 58\text{A}$ $I_g = 1.0\text{mA}$	-	28	42	nC
$Q_{g(TH)}$	Threshold Gate Charge	$V_{GS} = 0\text{V to } 2\text{V}$		-	3.5	5	nC
$Q_{gs}$	Gate to Source Gate Charge			-	11	-	nC
$Q_{gs2}$	Gate Charge Threshold to Plateau			-	7.6	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge			-	6.4	-	nC

### Switching Characteristics ( $V_{GS} = 10\text{V}$ )

$t_{ON}$	Turn-On Time	$V_{DD} = 40\text{V}, I_D = 58\text{A}$ $V_{GS} = 10\text{V}, R_{GS} = 10\Omega$	-	-	135	ns
$t_{d(ON)}$	Turn-On Delay Time		-	8	-	ns
$t_r$	Rise Time		-	82	-	ns
$t_{d(OFF)}$	Turn-Off Delay Time		-	28	-	ns
$t_f$	Fall Time		-	30	-	ns
$t_{OFF}$	Turn-Off Time		-	-	86	ns

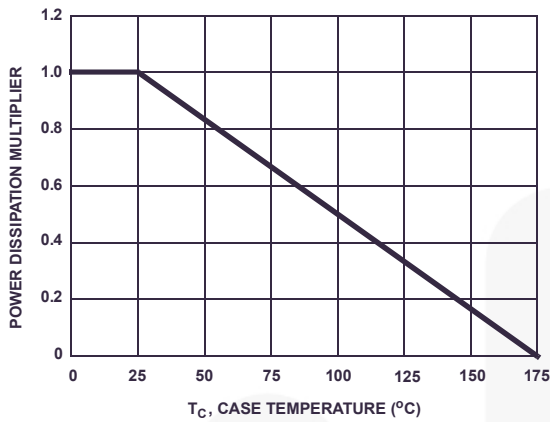
### Drain-Source Diode Characteristics

$V_{SD}$	Source to Drain Diode Voltage	$I_{SD} = 58\text{A}$	-	-	1.25	V
		$I_{SD} = 29\text{A}$	-	-	1.0	V
$t_{rr}$	Reverse Recovery Time	$I_{SD} = 58\text{A}, dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	-	35	ns
$Q_{RR}$	Reverse Recovered Charge	$I_{SD} = 58\text{A}, dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	-	36	nC

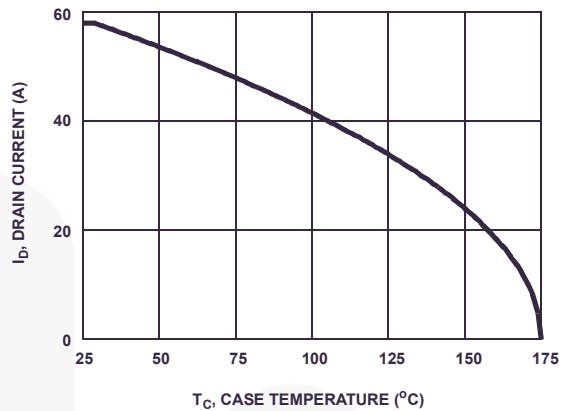
#### Notes:

1: Starting  $T_J = 25^\circ\text{C}$ ,  $L = 260\mu\text{H}$ ,  $I_{AS} = 30\text{A}$ .

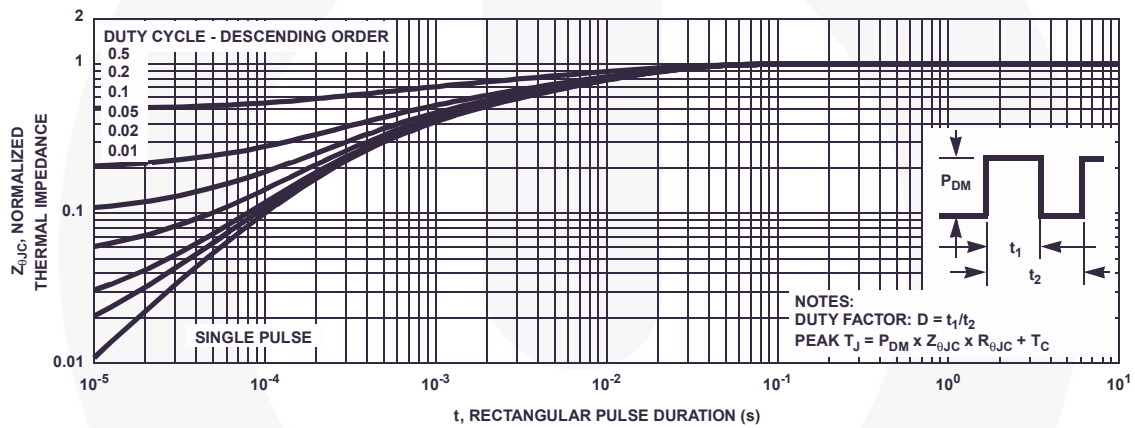
**Typical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted



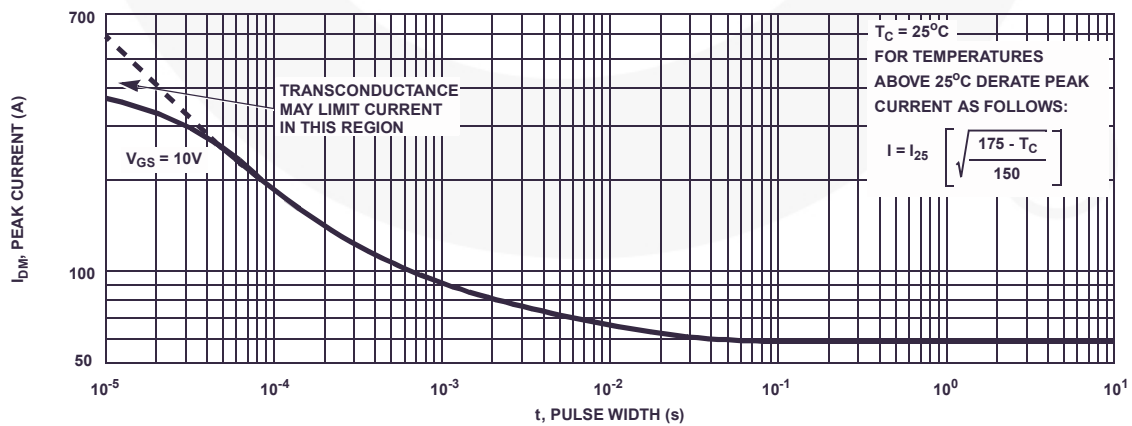
**Figure 1. Normalized Power Dissipation vs Ambient Temperature**



**Figure 2. Maximum Continuous Drain Current vs Case Temperature**

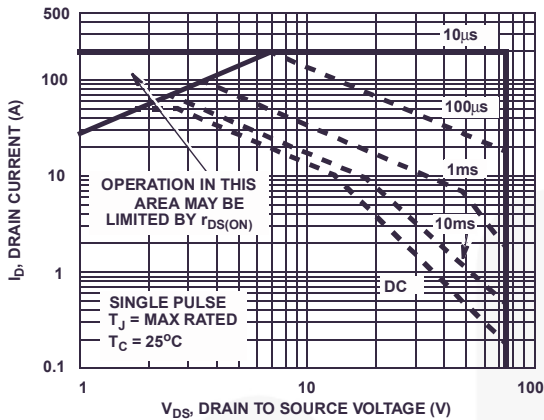


**Figure 3. Normalized Maximum Transient Thermal Impedance**

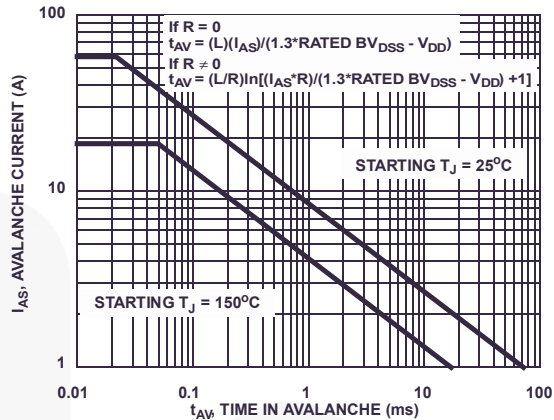


**Figure 4. Peak Current Capability**

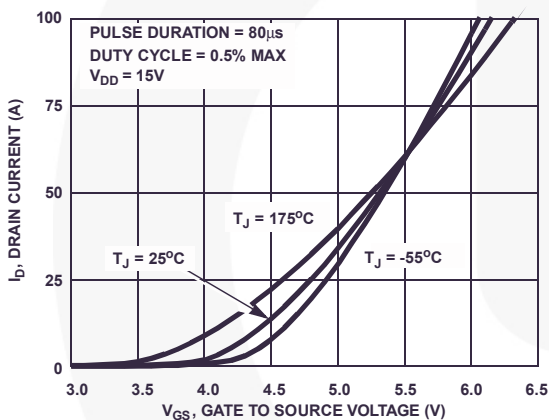
**Typical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted



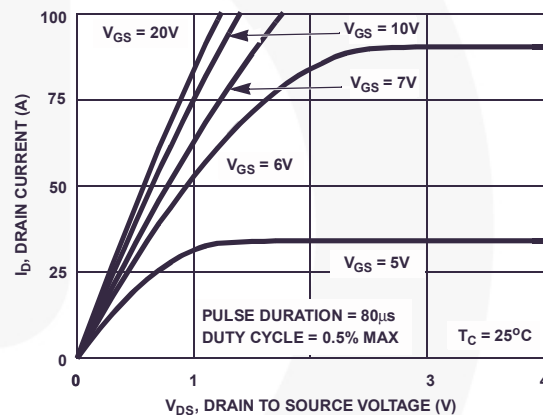
**Figure 5. Forward Bias Safe Operating Area**



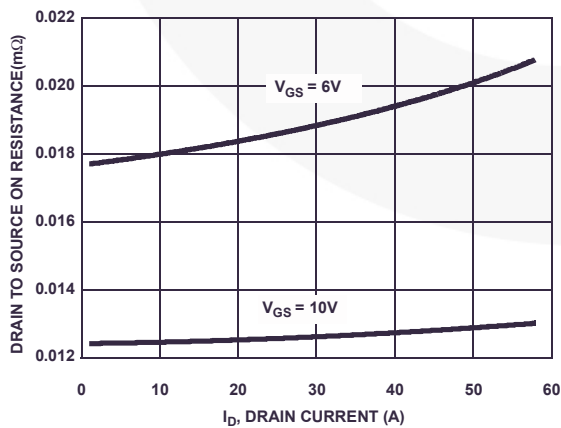
NOTE: Refer to Fairchild Application Notes AN7514 and AN7515  
**Figure 6. Unclamped Inductive Switching Capability**



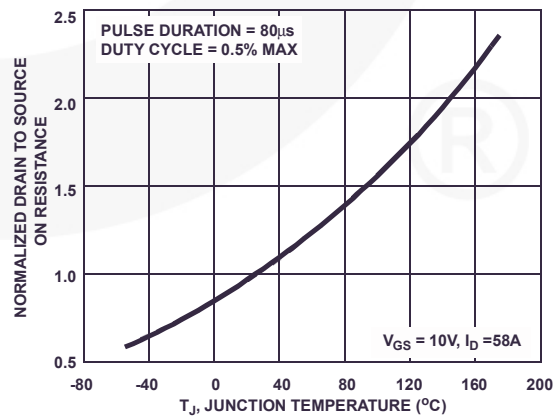
**Figure 7. Transfer Characteristics**



**Figure 8. Saturation Characteristics**

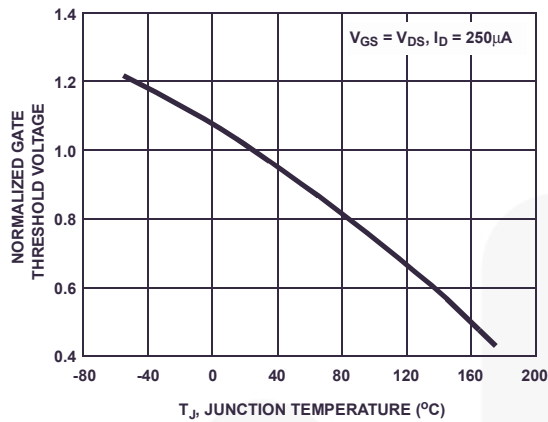


**Figure 9. Drain to Source On Resistance vs Drain Current**

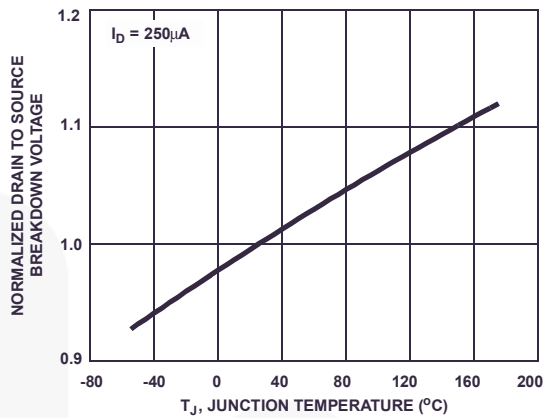


**Figure 10. Normalized Drain to Source On Resistance vs Junction Temperature**

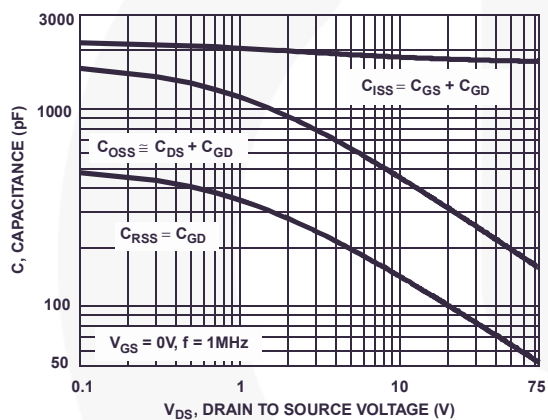
**Typical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted



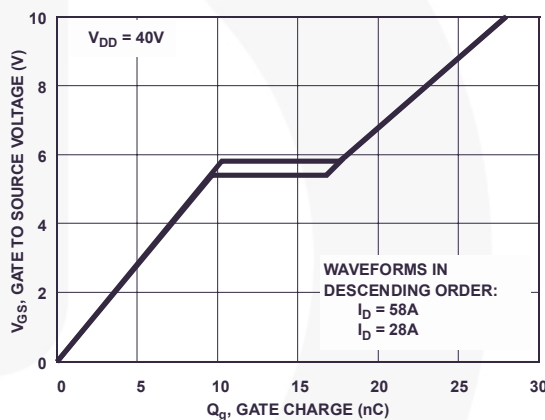
**Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature**



**Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature**



**Figure 13. Capacitance vs Drain to Source Voltage**



**Figure 14. Gate Charge Waveforms for Constant Gate Current**

### Test Circuits and Waveforms

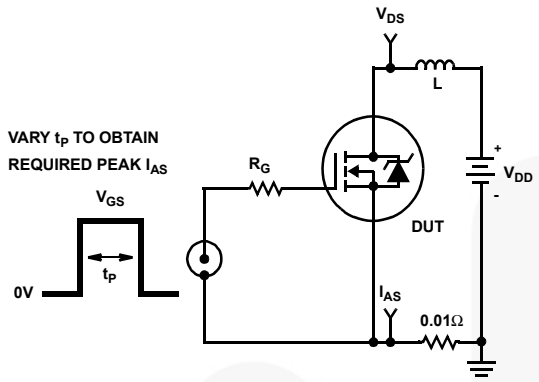


Figure 15. Unclamped Energy Test Circuit

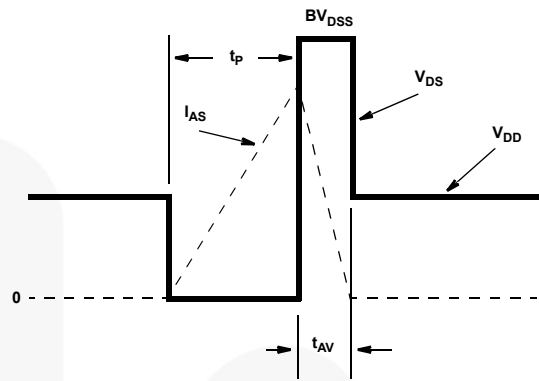


Figure 16. Unclamped Energy Waveforms

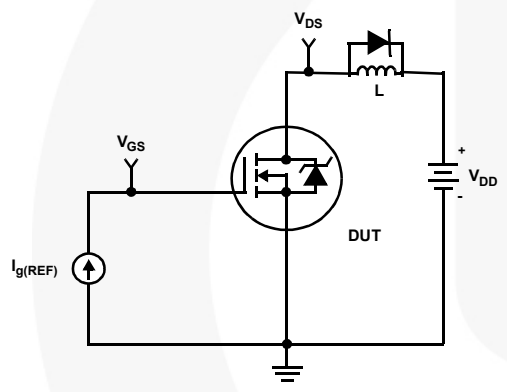


Figure 17. Gate Charge Test Circuit

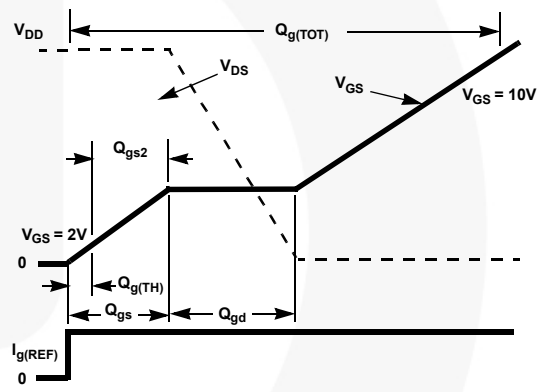


Figure 18. Gate Charge Waveforms

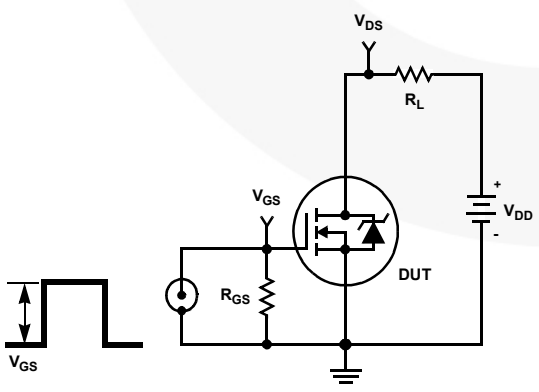


Figure 19. Switching Time Test Circuit

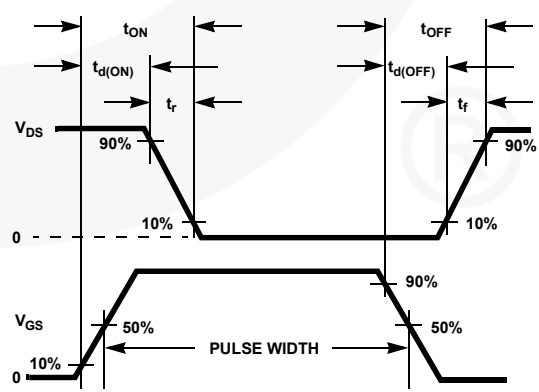


Figure 20. Switching Time Waveforms







**SPICE Thermal Model**

REV 23 March 2002

FDB16AN08A0T

CTHERM1 th 6 0.002  
 CTHERM2 6 5 0.004  
 CTHERM3 5 4 0.006  
 CTHERM4 4 3 0.01  
 CTHERM5 3 2 0.03  
 CTHERM6 2 tl 0.08

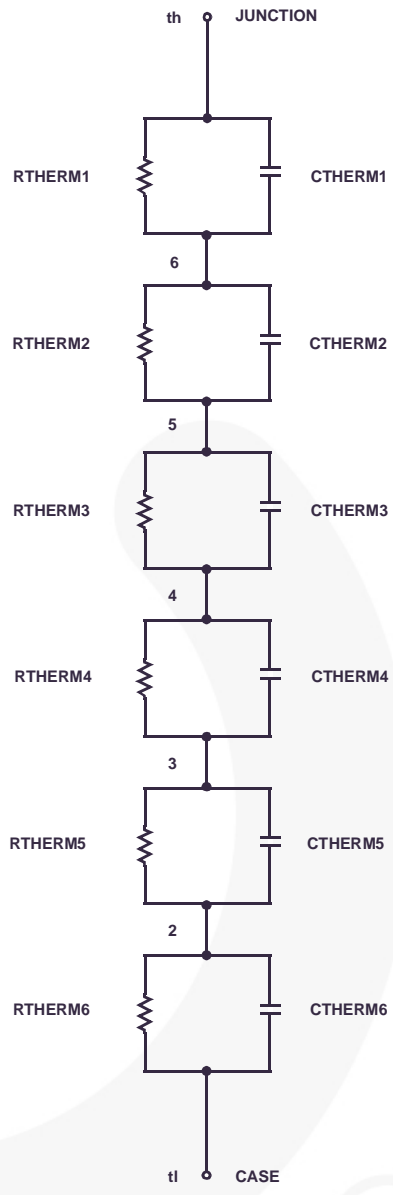
RTHERM1 th 6 0.075  
 RTHERM2 6 5 0.09  
 RTHERM3 5 4 0.1  
 RTHERM4 4 3 0.15  
 RTHERM5 3 2 0.2  
 RTHERM6 2 tl 0.25

**SABER Thermal Model**

SABER thermal model FDD16AN08A0T  
 template thermal\_model th tl  
 thermal\_c th, tl

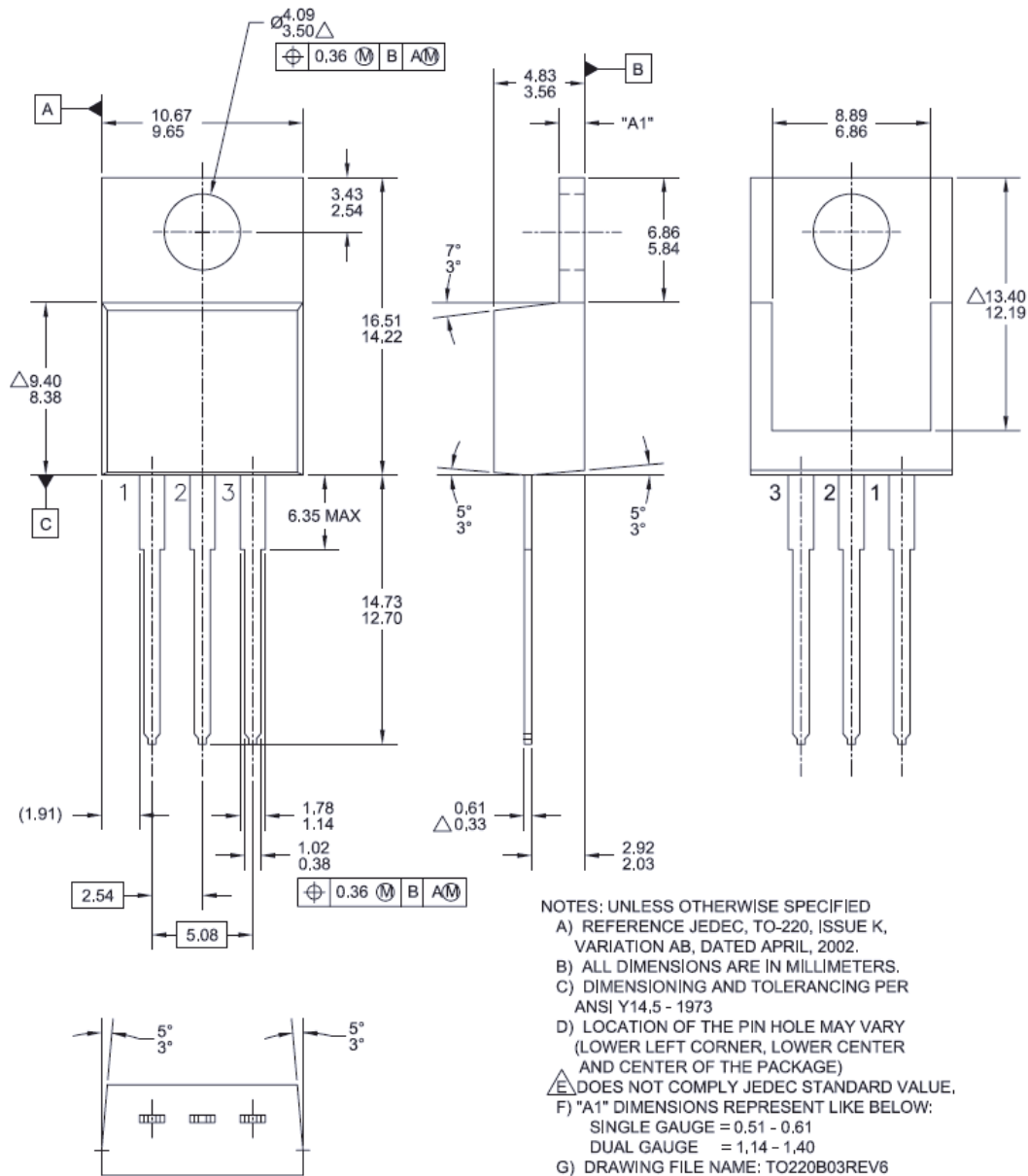
```
{
    ctherm.ctherm1 th 6 = 0.002
    ctherm.ctherm2 6 5 = 0.004
    ctherm.ctherm3 5 4 = 0.006
    ctherm.ctherm4 4 3 = 0.01
    ctherm.ctherm5 3 2 = 0.03
    ctherm.ctherm6 2 tl = 0.08
```

```
rtherm.rtherm1 th 6 = 0.075
rtherm.rtherm2 6 5 = 0.09
rtherm.rtherm3 5 4 = 0.1
rtherm.rtherm4 4 3 = 0.15
rtherm.rtherm5 3 2 = 0.2
rtherm.rtherm6 2 tl = 0.25
}
```



## Mechanical Dimensions

### TO-220 3L



**Figure 21. TO-220, Molded, 3Lead, Jedec Variation AB**

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Dimension in Millimeters



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| BitSiC™                  | Global Power ResourceSM | Programmable Active Droop™                      | TinyBoost®       |
| Build it Now™            | GreenBridge™            | QFET®   | TinyBuck®        |
| CorePLUS™                | Green FPS™              | QS™   | TinyCalc™        |
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